Unitized Semiconductor Devices - Page 1 of 1



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Inclosure Material:
Metal
Overall Length:
0.185 inches

Terminal Length:

0.562 inches

Overall Diameter:

0.370 inches

Component Name And Quantity:

2 transistor

Mounting Method:

Terminal

Terminal Circle Diameter:

0.230 inches

Features Provided:

Hermetically sealed case

Semiconductor Material:

Silicon all transistor

Voltage Rating In Volts Per Characteristic:

20.0 collector to base voltage/static/emitter open all transistor and 5.0 emitter to base voltage, static, collector open all transistor

Current Rating Per Characteristic:

50.00 milliamperes source cutoff current all transistor

Power Rating Per Characteristic:

0.45 watts small-signal input power, common-collector preset all transistor

Maximum Operating Tempurature Per Measurement Point:

125.0 degrees celsius ambient air

Special Features:

All transistor junction pattern arrangement: npn

Precious Material And Location:

Terminals gold

Precious Material:

Gold

Terminal Type And Quantity:

12 pin

Shelf Life:

N/a

Unit Of Measure:

Demilitarization:

No

Fiig:

A110a0